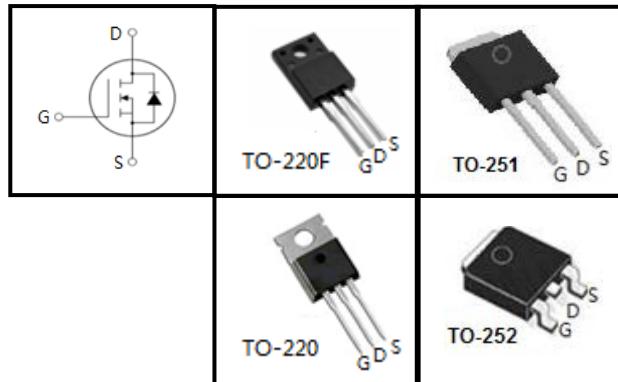


### FEATURES

- Very low FOM  $R_{DS(on)} \times Q_g$
- 100% avalanche tested
- RoHS compliant



### APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

| Device Marking and Package Information |           |           |           |           |
|--|-----------|-----------|-----------|-----------|
| Device                                 | SP65R940P |           |           |           |
| Package                                | TO-220    | TO-220F   | TO-251    | TO-252    |
| Marking                                | SP65R940P | SP65R940F | SP65R940U | SP65R940T |

### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ , unless otherwise noted

| Parameter  | Symbol         | Value                  |         | Unit |
|--|----------------|------------------------|---------|------|
|  |                | TO-251, TO-252, TO-220 | TO-220F |      |
| Drain-Source Voltage ( $V_{GS} = 0\text{V}$ )    | $V_{DSS}$      | 650                    |         | V    |
| Continuous Drain Current                         | $I_D$          | 4                      |         | A    |
| Pulsed Drain Current<br>(note1)                  | $I_{DM}$       | 12                     |         | A    |
| Gate-Source Voltage                              | $V_{GSS}$      | $\pm 30$               |         | V    |
| Single Pulse Avalanche Energy<br>(note2)         | $E_{AS}$       | 52.8                   |         | mJ   |
| Avalanche Current<br>(note1)                     | $I_{AR}$       | 0.8                    |         | A    |
| Repetitive Avalanche Energy<br>(note1)           | $E_{AR}$       | 0.09                   |         | mJ   |
| Power Dissipation ( $T_C = 25^\circ\text{C}$ )   | $P_D$          | 28                     | 23      | W    |
| Operating Junction and Storage Temperature Range | $T_J, T_{stg}$ | -55~+150               |         | °C   |

### Thermal Resistance

| Parameter                               | Symbol     | Value                  |         | Unit |
|---|------------|------------------------|---------|------|
|   |            | TO-251, TO-252, TO-220 | TO-220F |      |
| Thermal Resistance, Junction-to-Case    | $R_{thJC}$ | 4.4                    | 5.5     | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{thJA}$ | 62                     | 80      |      |

**Specifications**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

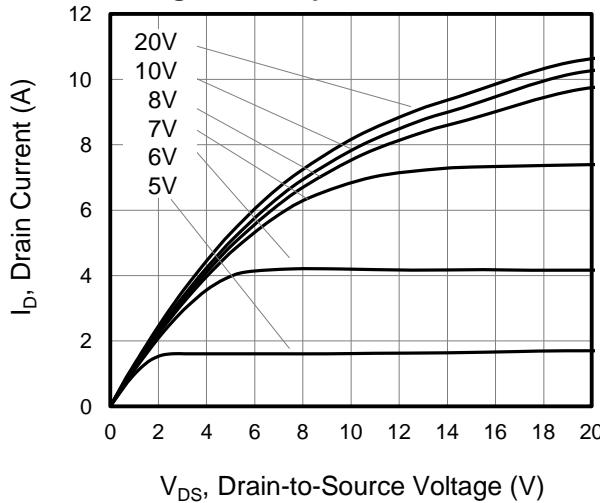
| Parameter                                      | Symbol                      | Test Conditions   | Value |      |           | Unit          |
|--|-----------------------------|---|-------|------|-----------|---------------|
|  |                             |   | Min.  | Typ. | Max.      |               |
| <b>Static</b>                                  |                             |   |       |      |           |               |
| Drain-Source Breakdown Voltage                 | $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$                                 | 650   | --   | --        | V             |
| Zero Gate Voltage Drain Current                | $I_{\text{DSS}}$            | $V_{\text{DS}} = 650\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 25^\circ\text{C}$  | --    | --   | 1         | $\mu\text{A}$ |
|  |                             | $V_{\text{DS}} = 650\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 150^\circ\text{C}$ | --    | --   | 100       |               |
| Gate-Source Leakage                            | $I_{\text{GSS}}$            | $V_{\text{GS}} = \pm 30\text{V}$  | --    | --   | $\pm 100$ | nA            |
| Gate-Source Threshold Voltage                  | $V_{\text{GS}(\text{th})}$  | $V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$                             | 2.5   | --   | 4.0       | V             |
| Drain-Source On-Resistance (Note3)             | $R_{\text{DS}(\text{on})}$  | $V_{\text{GS}} = 10\text{V}, I_D = 1\text{A}$                                     | --    | 0.88 | 1.0       | $\Omega$      |
| Forward Transconductance (Note3)               | $g_{\text{fs}}$             | $V_{\text{DS}} = 10\text{V}, I_D = 1\text{A}$                                     | --    | 3    | --        | S             |
| <b>Dynamic</b>                                 |                             |   |       |      |           |               |
| Input Capacitance                              | $C_{\text{iss}}$            | $V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 50\text{V}, f = 1.0\text{MHz}$        | --    | 350  | --        | $\text{pF}$   |
| Output Capacitance                             | $C_{\text{oss}}$            |   | --    | 20   | --        |               |
| Reverse Transfer Capacitance                   | $C_{\text{rss}}$            |   | --    | 2.6  | --        |               |
| Total Gate Charge                              | $Q_g$                       | $V_{\text{DD}} = 520\text{V}, I_D = 4\text{A}, V_{\text{GS}} = 10\text{V}$        | --    | 7    | --        | $\text{nC}$   |
| Gate-Source Charge                             | $Q_{\text{gs}}$             |   | --    | 1.5  | --        |               |
| Gate-Drain Charge                              | $Q_{\text{gd}}$             |   | --    | 2.5  | --        |               |
| Turn-on Delay Time                             | $t_{\text{d}(\text{on})}$   | $V_{\text{DD}} = 400\text{V}, I_D = 4\text{A}, R_G = 25\Omega$                    | --    | 36   | --        | $\text{ns}$   |
| Turn-on Rise Time                              | $t_r$                       |   | --    | 27   | --        |               |
| Turn-off Delay Time                            | $t_{\text{d}(\text{off})}$  |   | --    | 79   | --        |               |
| Turn-off Fall Time                             | $t_f$                       |   | --    | 29   | --        |               |
| <b>Drain-Source Body Diode Characteristics</b> |                             |   |       |      |           |               |
| Continuous Body Diode Current                  | $I_S$                       | $T_C = 25^\circ\text{C}$  | --    | --   | 3.9       | $\text{A}$    |
| Pulsed Diode Forward Current                   | $I_{\text{SM}}$             |   | --    | --   | 12        |               |
| Body Diode Voltage                             | $V_{\text{SD}}$             | $T_J = 25^\circ\text{C}, I_{\text{SD}} = 4\text{A}, V_{\text{GS}} = 0\text{V}$    | --    | 0.9  | 1.2       | V             |
| Reverse Recovery Time                          | $t_{\text{rr}}$             | $V_R = 480\text{V}, I_F = I_S, dI_F/dt = 100\text{A}/\mu\text{s}$                 | --    | 220  | --        | $\text{ns}$   |
| Reverse Recovery Charge                        | $Q_{\text{rr}}$             |   | --    | 0.9  | --        |               |
| Peak Reverse Recovery Current                  | $I_{\text{rrm}}$            |   | --    | 8    | --        | A             |

**Notes**

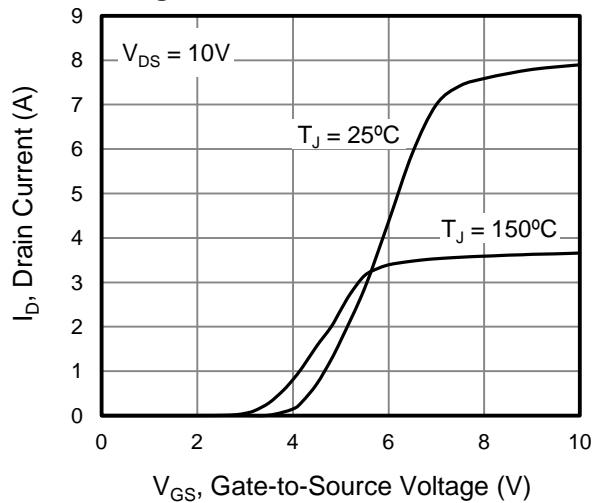
- Repetitive Rating: Pulse Width limited by maximum junction temperature
- $I_{AS} = 0.8\text{A}, V_{DD} = 50\text{V}, R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$
- Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 1\%$

**Typical Characteristics**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

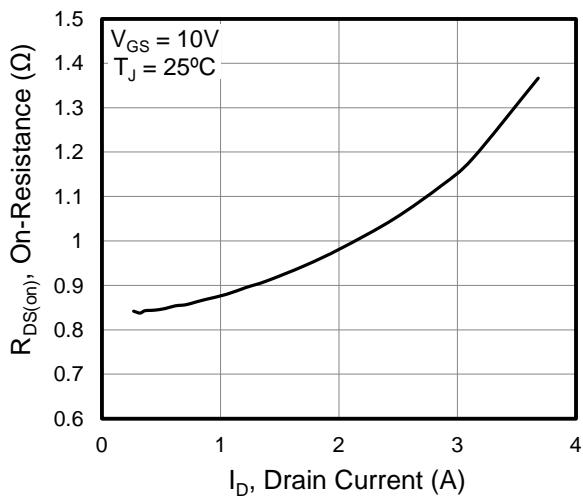
**Figure 1. Output Characteristics**



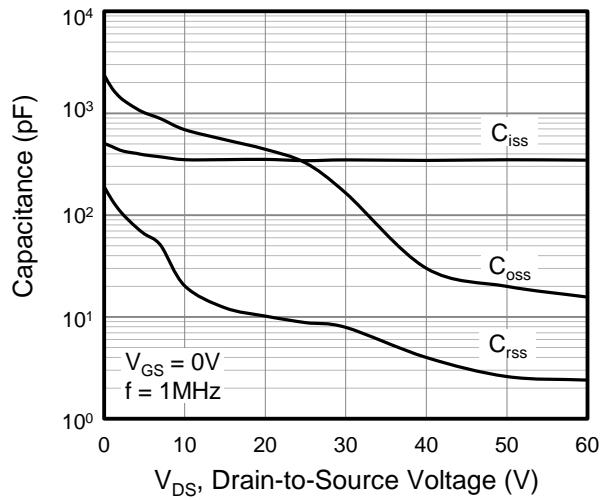
**Figure 2. Transfer Characteristics**



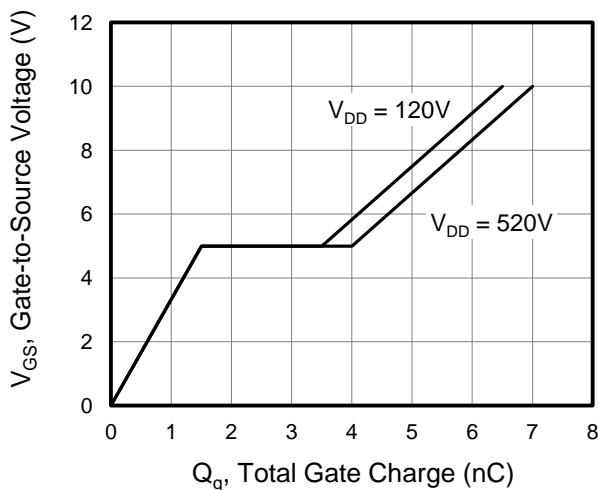
**Figure 3. On-Resistance vs. Drain Current**



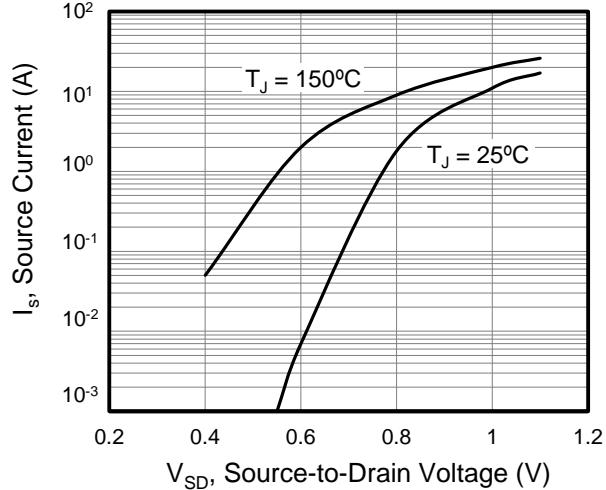
**Figure 4. Capacitance**



**Figure 5. Gate Charge**

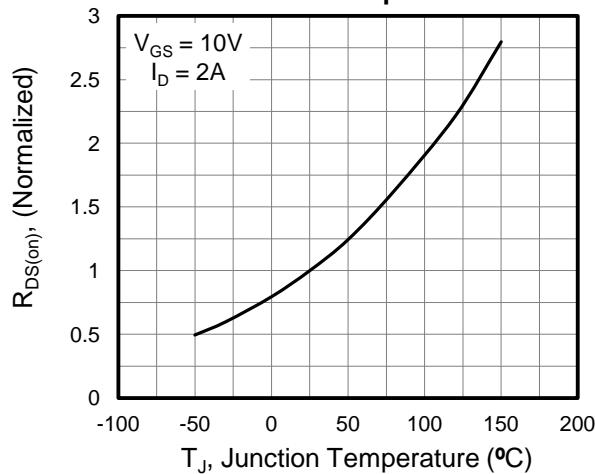


**Figure 6. Body Diode Forward Voltage**

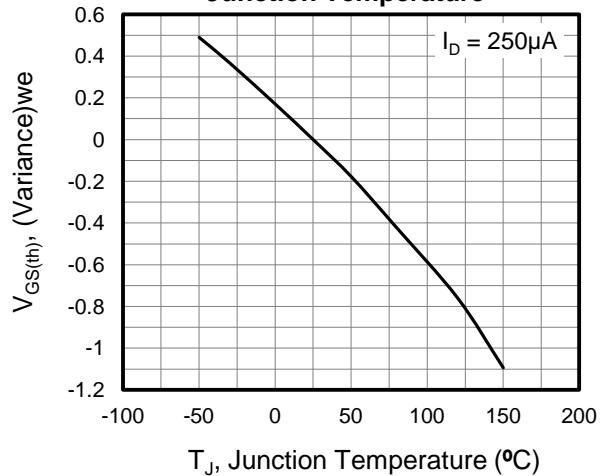


**Typical Characteristics**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

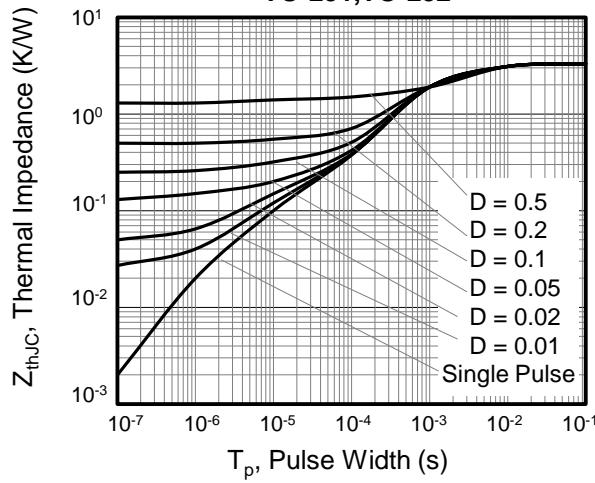
**Figure 7. On-Resistance vs.  
Junction Temperature**



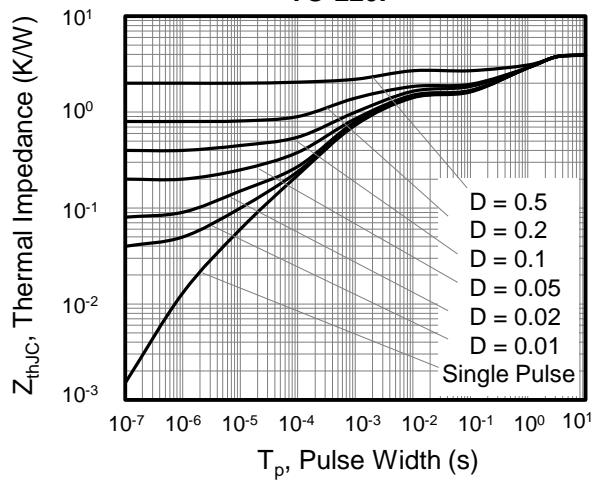
**Figure 8. Threshold Voltage vs.  
Junction Temperature**

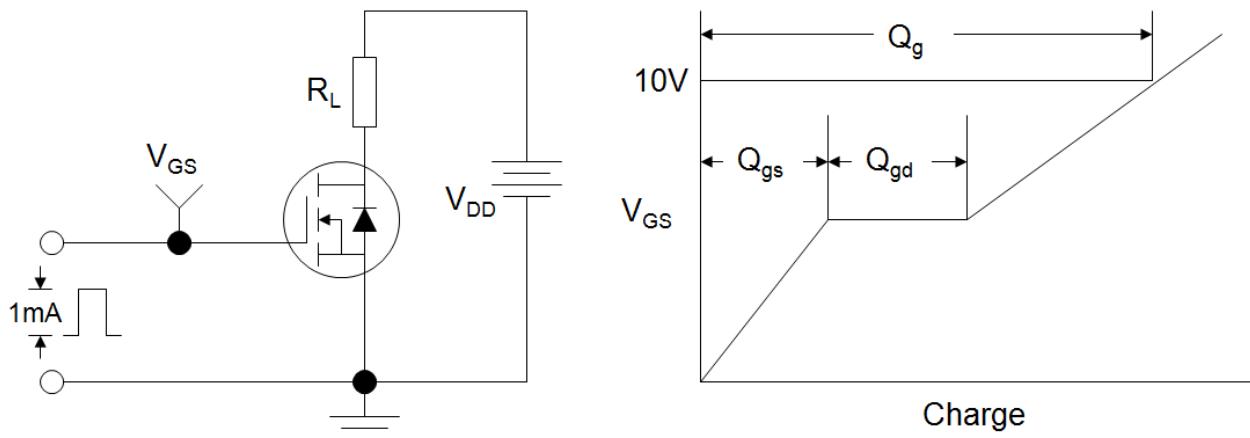
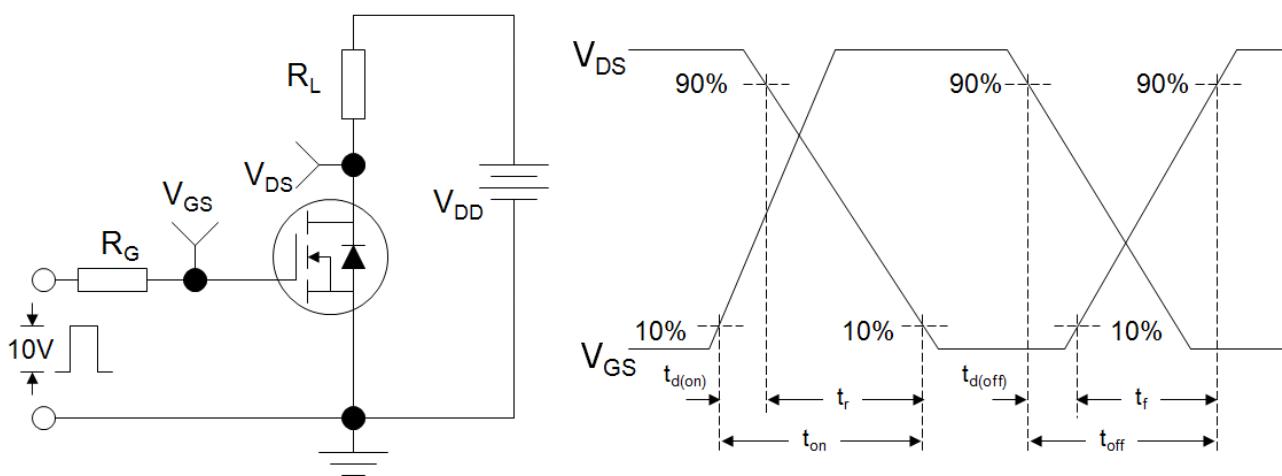
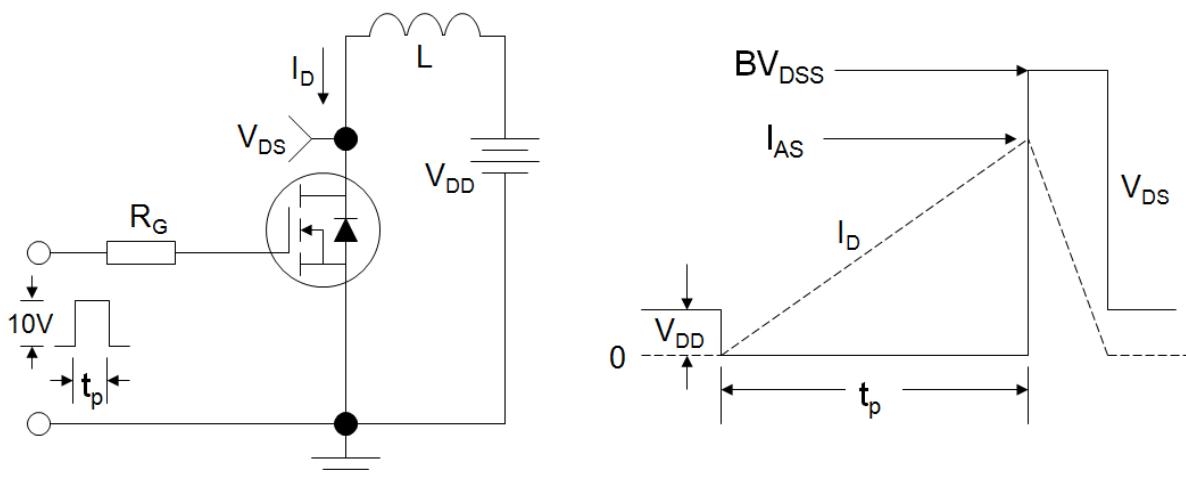


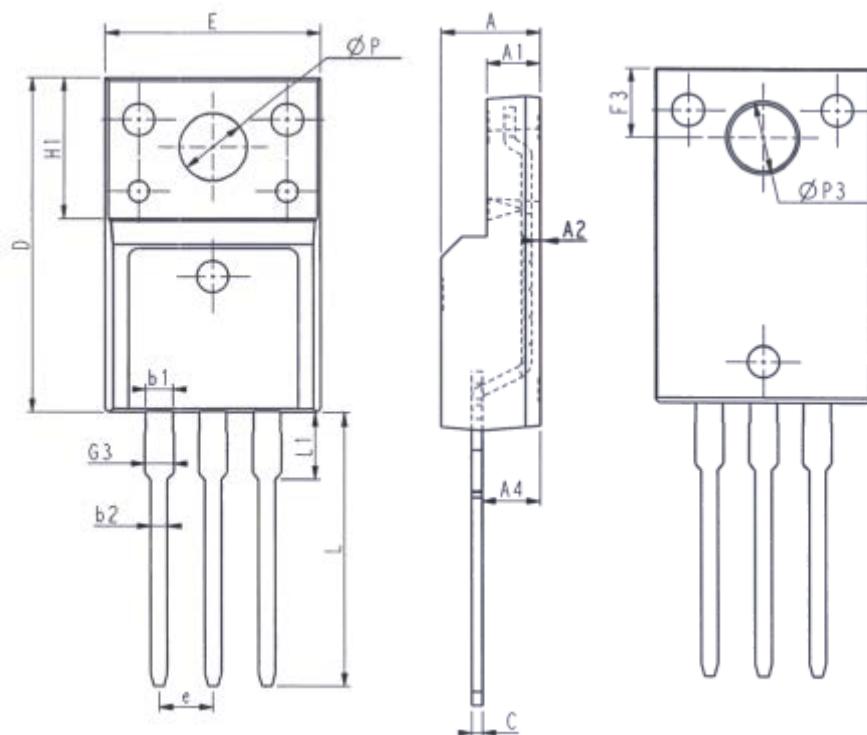
**Figure 9. Transient Thermal Impedance  
TO-251, TO-252**



**Figure 10. Transient Thermal Impedance  
TO-220F**



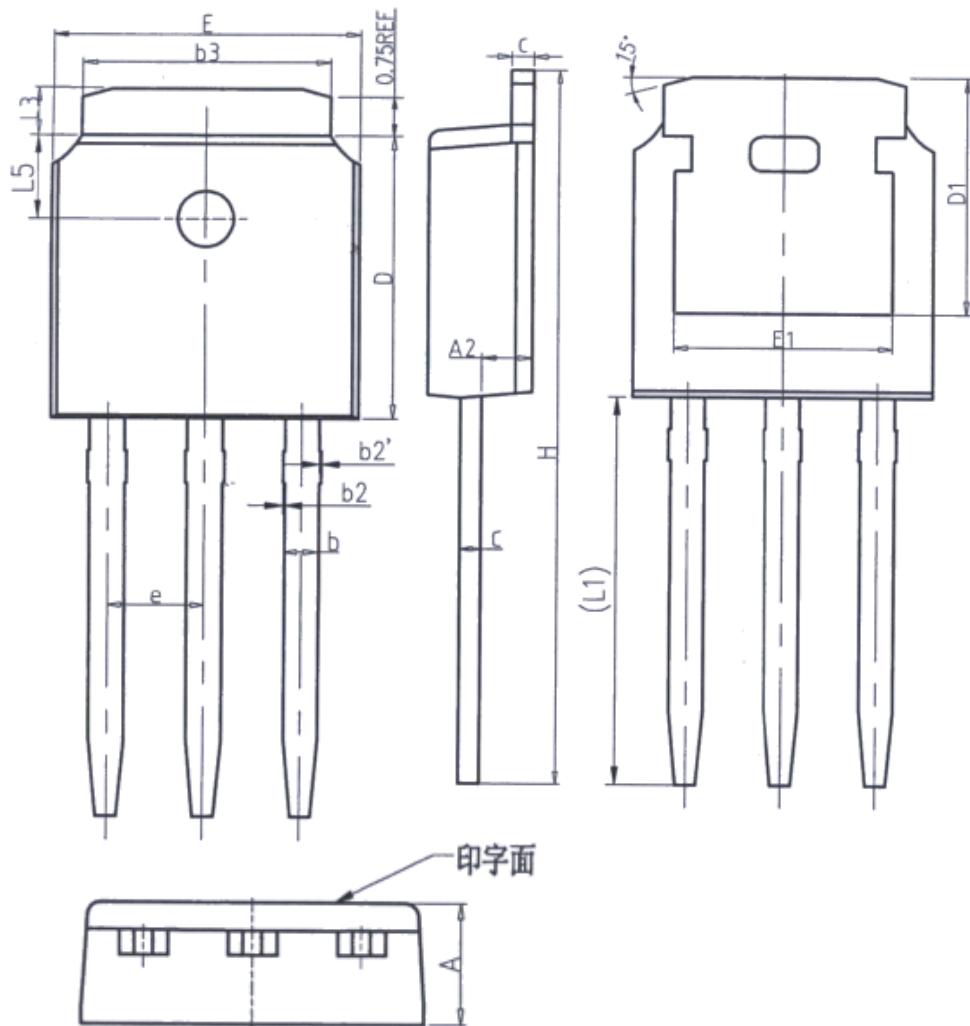
**Figure A: Gate Charge Test Circuit and Waveform**

**Figure B: Resistive Switching Test Circuit and Waveform**

**Figure C: Unclamped Inductive Switching Test Circuit and Waveform**


**TO-220F**


| Unit: mm |         |       |
|----------|---------|-------|
| Symbol   | Min.    | Max.  |
| E        | 9.96    | 10.36 |
| A        | 4.50    | 4.90  |
| A1       | 2.34    | 2.74  |
| A2       | 0.30    | 0.60  |
| A4       | 2.56    | 2.96  |
| c        | 0.40    | 0.65  |
| D        | 15.57   | 16.17 |
| H1       | 6.70REF |       |
| e        | 2.54BSC |       |

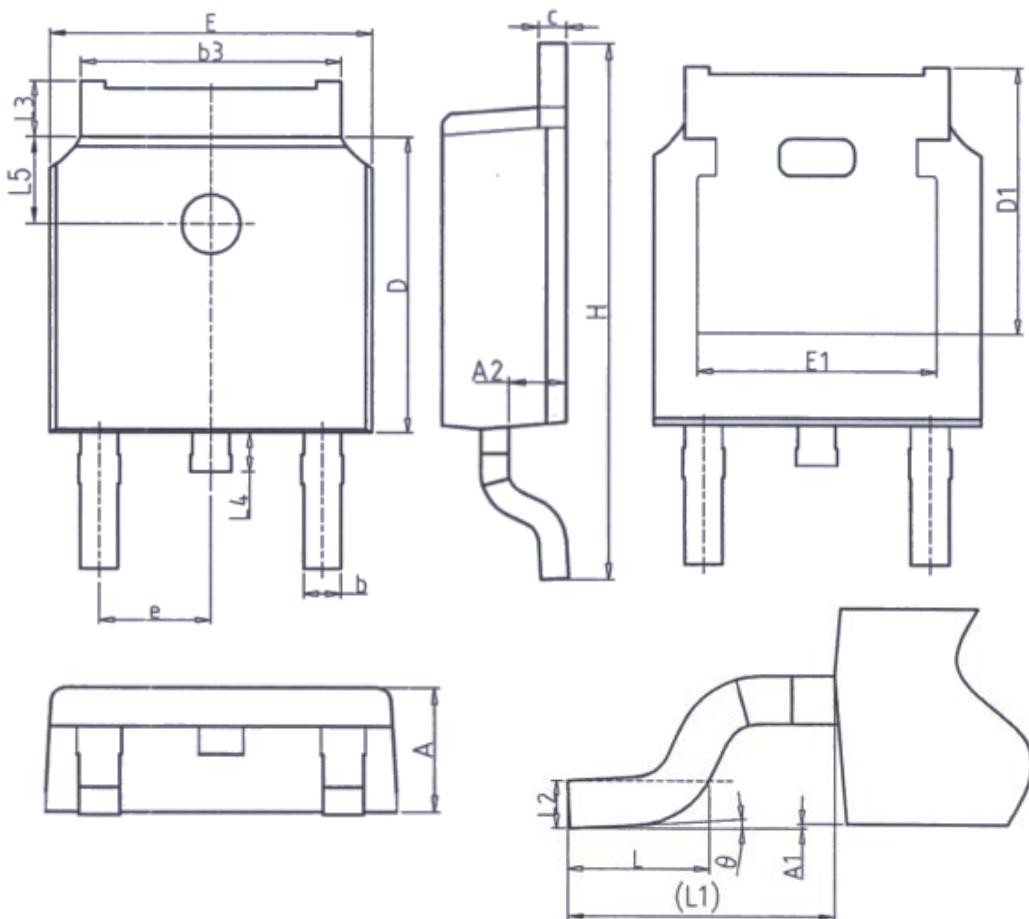
| Unit: mm |       |       |
|----------|-------|-------|
| Symbol   | Min.  | Max.  |
| L        | 12.68 | 13.28 |
| L1       | 2.93  | 3.13  |
| P        | 3.03  | 3.38  |
| P3       | 3.15  | 3.65  |
| F3       | 3.15  | 3.45  |
| G3       | 1.25  | 1.55  |
| b1       | 1.18  | 1.43  |
| b2       | 0.70  | 0.95  |

**TO-251**


| Unit: mm |      |      |
|----------|------|------|
| Symbol   | Min. | Max. |
| A        | 2.20 | 2.40 |
| A2       | 0.97 | 1.17 |
| b        | 0.68 | 0.90 |
| b2       | 0.00 | 0.10 |
| b2'      | 0.00 | 0.10 |
| b3       | 5.20 | 5.50 |
| c        | 0.43 | 0.63 |
| D        | 5.98 | 6.22 |

| Unit: mm |          |       |
|----------|----------|-------|
| Symbol   | Min.     | Max.  |
| D1       | 5.30REF  |       |
| E        | 6.40     | 6.80  |
| E1       | 4.63     | -     |
| e        | 2.286BSC |       |
| H        | 16.22    | 16.82 |
| L1       | 9.15     | 9.65  |
| L3       | 0.88     | 1.28  |
| L5       | 1.65     | 1.95  |

## TO-252



| Unit: mm |         |      |
|----------|---------|------|
| Symbol   | Min.    | Max. |
| A        | 2.20    | 2.40 |
| A1       | 0.00    | 0.20 |
| A2       | 0.97    | 1.17 |
| b        | 0.68    | 0.90 |
| b3       | 5.20    | 5.50 |
| c        | 0.43    | 0.63 |
| D        | 5.98    | 6.22 |
| D1       | 5.30REF |      |
| E        | 6.40    | 6.80 |
| E1       | 4.63    | -    |

| Unit: mm |          |       |
|----------|----------|-------|
| Symbol   | Min.     | Max.  |
| e        | 2.286BSC |       |
| H        | 9.40     | 10.50 |
| L        | 1.38     | 1.75  |
| L1       | 2.90REF  |       |
| L2       | 0.51BSC  |       |
| L3       | 0.88     | 1.28  |
| L4       | -        | 1.00  |
| L5       | 1.65     | 1.95  |
| θ        | 0°       | 8°    |